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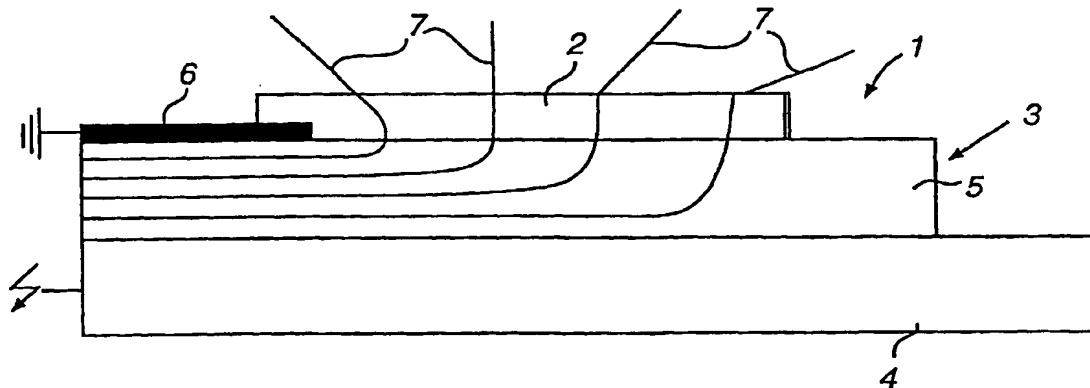
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(54) Title: FIELD GRADING MATERIAL



(57) Abstract: The present invention relates to a field grading material consisting of a polymeric matrix provided with a filler. The filler comprises a field grading effective amount of particles having at least one dimension smaller than or equal to 100 nm. The invention also relates to a device comprising such a field grading material for grading an electric field in high-voltage applications and a method for grading an electric field at a joint or termination of an electric power cable using such a field grading material.

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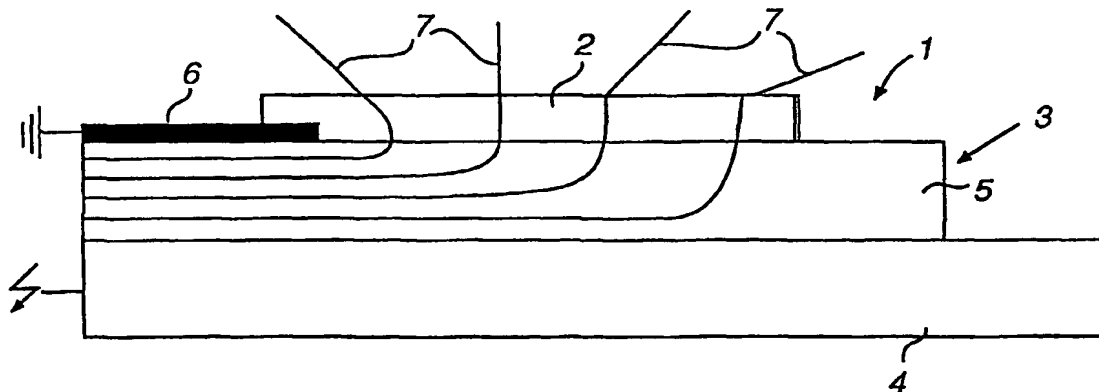
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(54) Title: FIELD GRADING MATERIAL



(57) Abstract: The present invention relates to a field grading material consisting of a polymeric matrix provided with a filler. The filler comprises a field grading effective amount of particles having at least one dimension smaller than or equal to 100 nm. The invention also relates to a device comprising such a field grading material for grading an electric field in high-voltage applications and a method for grading an electric field at a joint or termination of an electric power cable using such a field grading material.

### Field grading material

#### 10 TECHNICAL FIELD OF THE INVENTION AND PRIOR ART

The present invention relates to a field grading material consisting of a polymeric matrix provided with filler particles as well as a device for grading an electric field in high-voltage applications. The invention also relates to a method for grading an electric field at a joint or termination of an electric power cable.

At the transition of an electric field from a first medium to a second medium, electric stresses harmful to the electric equipment can ensue due to a discontinuity in the electric field. In a shielded high-voltage cable for instance, the electric field is uniform along the cable axis and there is variation in the field only in the radial direction. When the cable is terminated or spliced, the shield of the cable is removed for a distance along the cable. The removal of the shield causes a discontinuity in the electric field at the shield end, resulting in high electric stresses. These high stresses must be reduced in order not to impair the expected life of the system.

The electric stresses in question can be reduced by grading the electric field at the transition of the electric field from the first medium to the second medium, e.g. from a shielded cable part to a cable part where the original shield has been removed. A number of methods have been developed and employed for this kind of field grading. The present invention is related to so called resistive and capacitive field grading.

The resistive field grading can be used in alternating current as well as direct current applications. Resistive field grading can also be used in order to achieve field grading when voltages are occurring in the form of impulses. In case of a cable ending of the kind indicated above, a body having a suitable resistance is introduced around the unshielded part of the cable in the area closest to the shielded part of the cable and in electric contact with the shield. When a positive voltage is applied across the cable a current flows through the body towards the shield of the cable, which shield is at earth potential. A resistive voltage drop then occurs in the body, which results in a more uniform distribution of the potential. This potential distribution will be more linear if the body consists of a material exhibiting a non-linear electrical resistance that decreases with an increasing electric field. The closer to the edge of the shield, the higher the electric field in the field grading body and, consequently, the lower the electrical resistance in the body if the body exhibits such a non-linear electrical resistance. In this way, the voltage drop along the field grading body will become more uniformly distributed in a body that exhibits such a non-linear electrical resistance than in a body that does not..

The capacitive field grading is used in alternating current applications. Capacitive field grading can also be used in order to achieve field grading when voltages are occurring in the form of impulses. In case of a cable ending of the kind indicated above, a body of a material having a dielectric constant higher than that of the insulation and as low losses as possible is introduced around the unshielded part of the cable in the area closest to the shielded part of the cable and in electric contact with the shield, whereby a spreading of the equipotential lines will be achieved. Capacitive field grading properties are also desired in a material adapted for grading the electric field in high-voltage direct current applications so as to achieve an effective field grading in case of suddenly occurring voltage surges.

## SUMMARY OF THE INVENTION

5 The object of the present invention is to provide an improved field grading material of the type indicated in the preamble of claim 1.

According to the invention, this object is achieved by a material having the features of claim 1.

10

It has been found that the use of a filler essentially consisting of nanoscale particles, i.e. particles having at least one dimension smaller than or equal to 100 nm, results in percolation at a lower filler concentration in the material as compared to a corresponding material comprising a filler consisting of particles of larger size. Thus, with the material according to the invention, desired field grading properties can be obtained with a relatively low concentration of filler in the matrix, implying improved processability and improved mechanical properties of the field grading material. The lower the concentration of filler in the matrix, the better the processability and the better mechanical properties of the field grading material.

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Furthermore, the use of a filler essentially consisting of nanoscale particles results in increased electrical breakdown strength of the field grading material as compared to a corresponding material comprising a filler consisting of particles of larger size. The electrical breakdown strength of the field grading material also increases with decreasing filler concentration. Consequently, the invention makes it possible to achieve a field grading material having very high electrical breakdown strength and thus being well suited for high-voltage applications.

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In this description and the subsequent claims the term "nanosized particles" refers to particles having at least one dimension smaller than or equal to 100 nm, e.g. particles having a width,

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length and/or height smaller than or equal to 100 nm. The nano-sized particles may of course have several or all dimensions smaller than or equal to 100 nm. The nano-sized particles may e.g. be essentially spherical or cylindrical with a diameter  
5 smaller than or equal to 100 nm. It is emphasised that the nano-sized particles of the filler may have any shape as long as they in at least one of their dimensions are smaller than or equal to 100 nm.

10 In this description and the subsequent claims the term "field grading effective amount of filler particles" refers to an amount of filler particles that is sufficient for giving the material the desired field grading properties.

15 According to a preferred embodiment of the invention, the filler comprises a field grading effective amount of particles having one dimension between 2-80 nm, preferably 5-50 nm and most preferably 5-30 nm. It has been found that the above indicated advantages of the inventional field grading material are further  
20 improved when the size of the filler particles decreases from 100 nm and downwards. However, it is considered that a dimension of about 2 nm of the particles is the practical lower limit. If the particles are smaller than that, it will be very difficult to disperse the particles in the material and to prevent the particles from  
25 agglomerating.

A filler exhibits an essential increase in surface area per unit volume when the dimension of the particles in the filler decreases from 100 nm and downwards. The surface area per unit  
30 volume of the filler as a function of the particle size is illustrated in Fig 1 for spherical filler particles that are fully dispersed in a matrix material. This increase of the surface area per unit volume is believed to be an important reason for the beneficial effects associated with the field grading material according to the  
35 invention.

Further preferred embodiments of the field grading material according to the invention will appear from the dependent claims and the subsequent description.

- 5 The invention also relates to a device for grading an electric field in high-voltage applications according to claim 12.

The invention also relates to a method for grading an electric field at a joint or termination of an electric power cable according to claim 13.

#### BRIEF DESCRIPTION OF THE DRAWINGS

With reference to the enclosed drawings, a more specific description of embodiment examples of the invention will follow hereinbelow.

In the drawings

20

Fig 1 is a diagram showing the surface area per unit volume as a function of the particle size for particles, fully dispersed in a matrix material, having a spherical shape,

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Fig 2 is a diagram showing the electrical resistivity of different field grading materials as a function of filler concentration,

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Fig 3 is a diagram showing the electrical breakdown strength of different field grading materials as a function of filler concentration,

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Fig 4 is a diagram showing the dielectric constant (permittivity) of different field grading materials at 1 kHz as a function of filler concentration,



Fig 5 is a diagram showing the electrical resistivity of different SiC fillers as a function of electric field strength, and

5

Fig 6 is a schematic longitudinal sectional of a termination of an electric power cable, provided with a body of field grading material according to the invention.

## 10 DETAILED DESCRIPTION OF PREFERRED EMBODIMENTS OF THE INVENTION

The field grading material according to the present invention consists of a polymeric matrix provided with a filler. The filler  
15 comprises a field grading effective amount of particles having at least one dimension smaller than or equal to 100 nm.

The surface area per unit volume of a filler comprising spherical particles as a function of the particle size is illustrated in Fig 1.  
20 From the diagram of Fig 1, it can be seen that a filler exhibits an essential increase in surface area per unit volume of a fully dispersed filler when the dimension of the particles in the filler decreases from 100 nm and downwards. The gradient of the curve  $C_1$  showing the surface area per unit volume of a filler as  
25 a function of the particle size increases rapidly as the size of the particles is gradually reduced below 100 nm. It has been found that several important properties associated with the field grading effects of a field grading material of the above-indicated kind are essentially and surprisingly improved as the dimension of  
30 the particles in the filler is reduced below 100 nm.

The polymeric matrix in the field grading material according to the invention is suitably provided with a filler comprising a field  
grading effective amount of particles having at least one dimension  
35 between 2-80 nm, preferably 5-50 nm and most preferably 5-30 nm.

Fig 2 is a diagram showing the electrical resistivity of some different field grading materials as a function of filler concentration (percentage by volume). A first curve  $C_{21}$  is related to a field grading material consisting of a matrix of LDPE provided with a filler of ZnO-particles having an average size of about 0,3  $\mu\text{m}$  (300 nm). A second curve  $C_{22}$  is related to a field grading material consisting of a matrix of LDPE provided with a filler of ZnO-particles having an average size of about 49 nm. A third curve  $C_{23}$  is related to a field grading material consisting of a matrix of LDPE provided with a filler of ZnO-particles having an average size of about 24 nm. It is evident from this diagram that percolation begins at an essentially lower filler concentration for the materials comprising nano-sized filler particles (curves  $C_{22}$  and  $C_{23}$ ) as compared to the material comprising micro-sized filler particles (curve  $C_{21}$ ). For the materials related to the curves  $C_{22}$  and  $C_{23}$  percolation begins at a filler concentration of about 12% by volume and 15% by volume, respectively, whereas percolation begins at a filler concentration of about 28% by volume for the material related to the curve  $C_{21}$ . The smaller the size of the particles, the lower the filler concentration required for percolation.

Fig 3 is a diagram showing the electrical breakdown strength of two different field grading materials as a function of filler concentration (percentage by volume). One of the sets of measured data points in Fig 3 is related to a field grading material consisting of a matrix of LDPE provided with a filler of ZnO-particles having an average size of about 0,3  $\mu\text{m}$  (i.e. micro-sized particles). The other set of measured data points in Fig 3 is related to a field grading material consisting of a matrix of LDPE provided with a filler of ZnO-particles having an average size of about 50 nm (i.e. nano-sized particles). It can be seen in this diagram that the material comprising nano-sized filler particles has a higher electrical breakdown strength than the material comprising micro-sized filler particles at a given filler concentra-

tion. Consequently, a higher electrical breakdown strength of a field grading material can be obtained when using nano-sized filler particles as compared to using micro-sized filler particles. Thus, a field grading material comprising nano-sized particles is  
5 suitable for high-voltage applications. It can also be seen in the diagram that the electrical breakdown strength of the respective field grading material increases with decreasing filler concentration.

- 10 The nano-sized filler particles suitably constitute less than 40% by volume, preferably less than 30% by volume and most preferably less than 20% by volume of the field grading material.

15 The polymeric matrix of the field grading material according to the present invention suitably consists, or at least essentially consists, of rubber, thermoplastics or thermoplastic elastomer. It is preferred that the matrix consists, or at least essentially consists, of polyolefin rubber or thermoplastic polyolefin elastomer/plastomer, preferably including EPDM (Ethylene Propyl-  
20 ene Diene Monomer) rubber or silicone rubber, or of crystalline thermoplastics, preferably polyethylene.

The nano-sized filler particles are suitably dispersed in the polymeric matrix by ordinary melt-mixing.

25

According to a first variant of the invention, the filler is of a material where the bulk has a dielectric constant at infinitely high frequencies of at least 5, preferably  $\text{Al}_2\text{O}_3$ ,  $\text{TiO}_2$  or  $\text{BaTiO}_3$ . This implies that the field grading material has effective capacitive  
30 field grading properties in possible combination with resistive field grading properties. It is previously known that the dielectric constant of a material consisting of a polymeric matrix with filler is fairly independent of the size of the high dielectric constant particles of the filler. However, it has surprisingly been found  
35 that there is a dramatic increase in the dielectric constant when the size of the particles in the filler is decreased to such an ex-

tent that the particles have one dimension smaller than or equal to 100 nm. Therefore, by decreasing the size of the high dielectric constant particles in the filler to such an extent that the particles have one dimension smaller than or equal to 100 nm, a field grading material having a desired dielectric constant can be obtained with a filler concentration being essentially lower as compared to a corresponding material comprising a filler consisting of particles of larger size.

Fig 4 is a diagram showing the dielectric constant (permittivity) of two different field grading materials, which are subjected to an alternating voltage having a frequency of 1 kHz, as a function of filler concentration (percentage by volume). One of the sets of measured data points in Fig 4 is related to a field grading material consisting of a matrix of Engage<sup>®</sup> provided with a filler of Al<sub>2</sub>O<sub>3</sub>-particles having an average size larger than 100 nm, i.e. micro-sized particles. The other set of measured data points in Fig 4 is related to a field grading material consisting of a matrix of Engage<sup>®</sup> provided with a filler of Al<sub>2</sub>O<sub>3</sub>-particles having an average size of about 33 nm, i.e. nano-sized particles. It can be seen in this diagram that the material comprising nano-sized filler particles has a higher dielectric constant than the material comprising micro-sized filler particles at a given filler concentration.

According to a second variant of the invention, the filler is of a semiconducting material, i.e. a material having an energy band-gap larger than 0 eV and smaller than about 5 eV, preferably ZnO or SiC. The use of semiconducting filler materials, such as ZnO or SiC, normally results in a non-linear electrical resistance of the field grading material, i.e. a resistance that decreases with an increasing electric field. This non-linearity of the resistance can be favourable in certain applications as previously indicated. The onset of the non-linearity of the resistance, i.e. the electrical field strength at which the resistance changes from an essentially linear to an essentially non-linear behaviour, in-

creases with decreasing size of the particles in the filler. Thus, a material according to this variant of the invention exhibits an onset of the non-linearity of the resistance being at a higher field strength as compared to a corresponding material comprising a filler consisting of particles of larger size. When the onset of the non-linearity of the resistance is at a higher field strength, reliable resistive field grading at high electrical fields becomes possible. This may be combined with suitable capacitive field grading properties.

Fig 5 is a diagram showing the electrical resistivity of different SiC fillers as a function of electric field strength. One of the sets of measured data points in Fig 5 is related to a pure SiC powder comprising SiC particles having an average size of about 10  $\mu\text{m}$ , i.e. micro-sized particles. The other set of measured data points in Fig 5 is related to a pure SiC powder comprising SiC particles having an average size of about 20 nm, i.e. nano-sized particles. It can be seen in this diagram that the material comprising nano-sized particles exhibits an onset of the non-linearity of the resistance being at a higher electric field strength, about 10 kV/cm, as compared to the material comprising micro-sized particles, for which the onset of the non-linearity of the resistance is below 1 kV/cm.

For a material comprising particles of micro-size and larger, the onset of the non-linearity of the resistance is essentially reciprocally proportional to the particle size. It has however been noticed that the onset of the non-linearity of the resistance is not reciprocally proportional to the particle size for a material comprising particles of nano-size. This is advantageous since the onset of the non-linearity of the resistance would have been at a far too high electric field strength for a material comprising a filler of nano-sized particles if the reciprocal proportionality had applied also for nano-sized particles.

According to a preferred embodiment of the invention, the nano-sized filler particles essentially have a high aspect ratio, i.e. an aspect ratio of more than 1, preferably more than 5 and most preferably more than 10. Said particles may be provided in the form of fibres, fibrils, whiskers, flakes, tubes, ellipsoids etc.

If the particles having a high aspect ratio are randomly oriented in the matrix, an isotropic field grading material is obtained. The use of such particles randomly oriented in the matrix results in percolation at a lower filler concentration as compared to a corresponding material comprising a filler consisting of particles having essentially a spherical shape.

If the particles having a high aspect ratio are oriented to extend essentially in the same direction in the matrix, i.e. if they are oriented in a specific preferred direction in the matrix, an anisotropy in field grading properties is conferred to the field grading material, which anisotropy can be favourable in certain applications.

A field grading material according to the invention is suitable for use at a joint or termination of an electric power cable, in which case a body comprising the field grading material is introduced in the cable joint or cable termination. Fig 6 schematically illustrates a cable termination 1 provided with a body 2 of field grading material according to the present invention. The cable 3 comprises a conductor 4 surrounded by an insulation 5. A shield 6 is arranged outside the insulation 5, said shield being connected to ground. The end of the cable 3 is unshielded, i.e. at the end of the cable the insulation 5 is not covered by any shield. The body 2 of field grading material is introduced around the unshielded part of the cable in the area closest to the shielded part of the cable and in electric contact with the shield 6. The body 2 of field grading material will secure a uniform distribution of the potential at the cable termination, as illustrated

by the equipotential lines 7 in Fig 6. Only the upper half of the longitudinal section of the cable termination is shown in Fig 6.

5 A field grading material according to the invention is particularly suitable for use in a device for grading an electric field in high-voltage applications. Such a device could e.g. comprise a body 2 of the type illustrated in Fig 6 for use at a cable termination or cable joint or in any other type of application where a grading of an electric field is required.

10

The invention is of course not in any way limited to the preferred embodiments described above. On the contrary, several possibilities to modifications thereof should be evident to a person skilled in the art, without deviating from the basic idea of the invention as defined in the appended claims. It is for instance possible to include an additional smaller amount of micro-sized filler particles in the matrix, as long as the essential field grading effects are defined by the nano-sized filler particles included in the matrix.

20

## CLAIMS

1. A field grading material consisting of a polymeric matrix provided with a filler, characterized in that the filler comprises a field grading effective amount of particles having at least one dimension smaller than or equal to 100 nm.  
5
2. A field grading material according to claim 1, characterized in that the filler comprises a field grading effective amount of particles having one dimension between 2-80 nm, preferably 5-50 nm and most preferably 5-30 nm.  
10
3. A field grading material according to claim 1 or 2, characterized in that said particles are of any semiconducting material having an energy bandgap larger than 0 eV and smaller than 5 eV, preferably ZnO or SiC.  
15
4. A field grading material according to claim 1 or 2, characterized in that said particles are of any material where the bulk has a dielectric constant at infinitely high frequencies of at least 5, preferably Al<sub>2</sub>O<sub>3</sub>, TiO<sub>2</sub> or BaTiO<sub>3</sub>.  
20
5. A field grading material according to any of the preceding claims, characterized in that said particles are particles having an aspect ratio of more than 1, preferably of more than 5 and most preferably of more than 10.  
25
6. A field grading material according to claim 5, characterized in that the particles having an aspect ratio of more than 1, preferably of more than 5 and most preferably of more than 10, are randomly oriented in the matrix.  
30
7. A field grading material according to claim 5, characterized in that the particles having an aspect ratio of more than 1, preferably of more than 5 and most preferably of more than  
35



10, are oriented in essentially the same direction in the matrix.

- 5 8. A field grading material according to any of claims 5-7, characterized in that said particles having an aspect ratio of more than 1, preferably of more than 5 and most preferably of more than 10, are provided in the form of fibres, fibrils, whiskers, flakes, ellipsoids or tubes.
- 10 9. A field grading material according to any of the preceding claims, characterized in that said particles constitute less than 40% by volume, preferably less than 30% by volume and most preferably less than 20% by volume of the field grading material.
- 15 10. A field grading material according to any of the preceding claims, characterized in that the matrix essentially consists of rubber, thermoplastics or thermoplastic elastomer.
- 20 11. A field grading material according to claim 10, characterized in that the matrix essentially consists of polyolefin rubber or thermoplastic polyolefin elastomer/plastomer, preferably including EPDM (Ethylene Propylene Diene Monomer) rubber or silicone rubber, or of crystalline thermoplastics, preferably
- 25 polyethylene.
- 30 12. A device for grading an electric field in high-voltage applications, characterized in that the device comprises a field grading material according to any of claims 1-11.
- 35 13. A method for grading an electric field at a joint or termination of an electric power cable, characterized in that a body of a field grading material according to any of claims 1-11 is introduced in the cable joint or cable termination.

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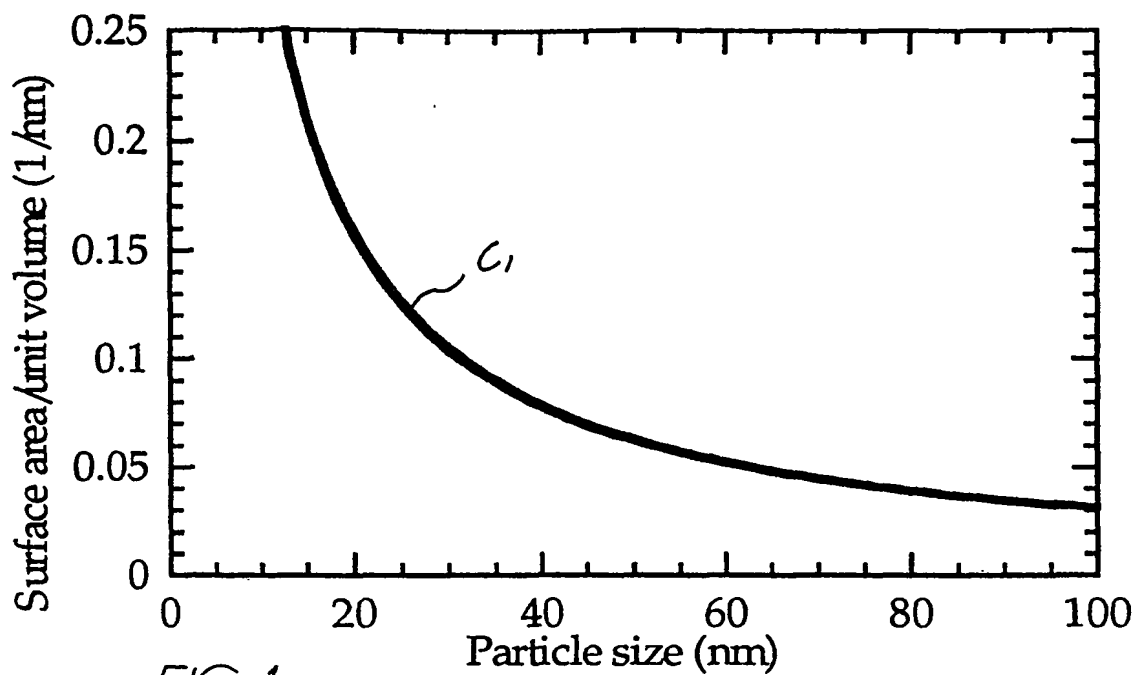


FIG 1

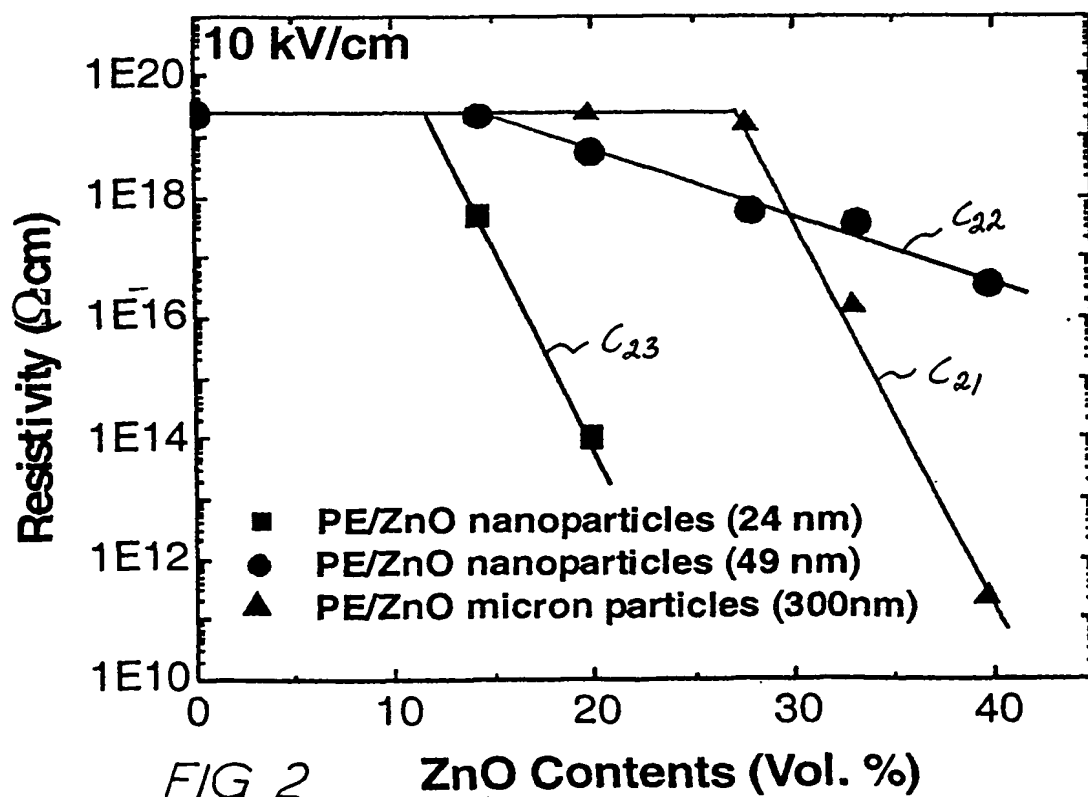


FIG 2

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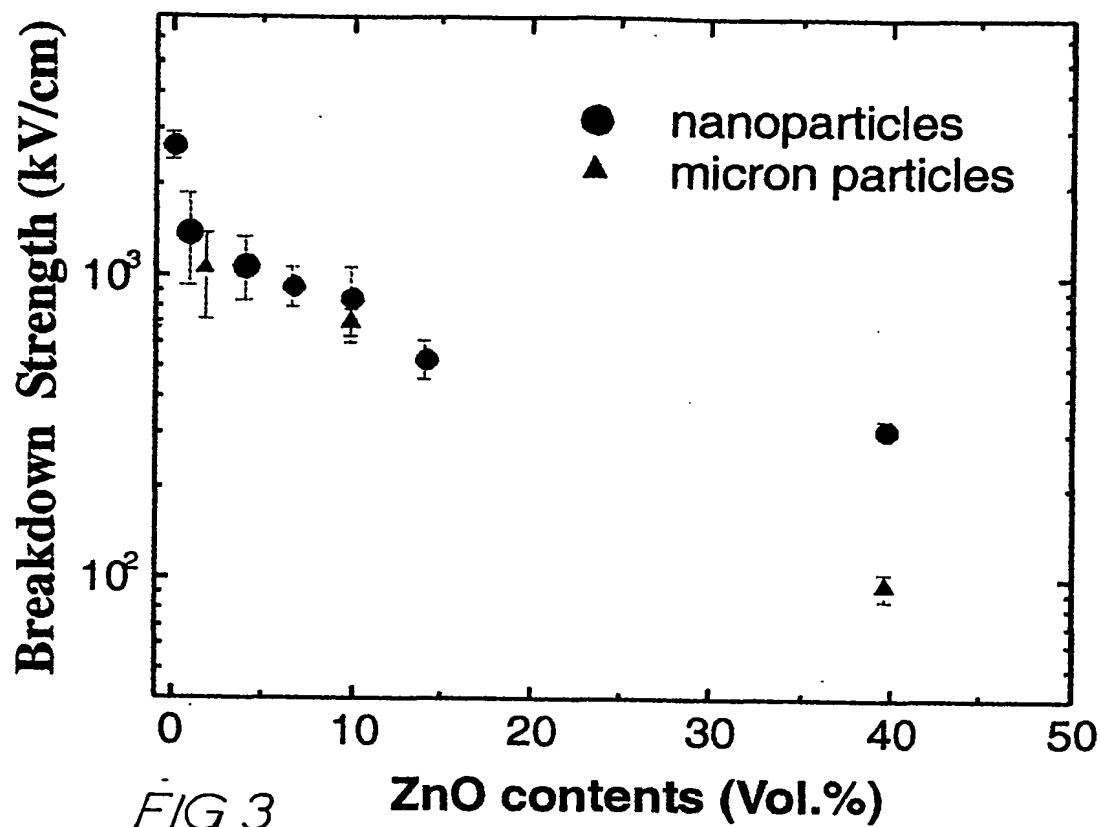


FIG 3

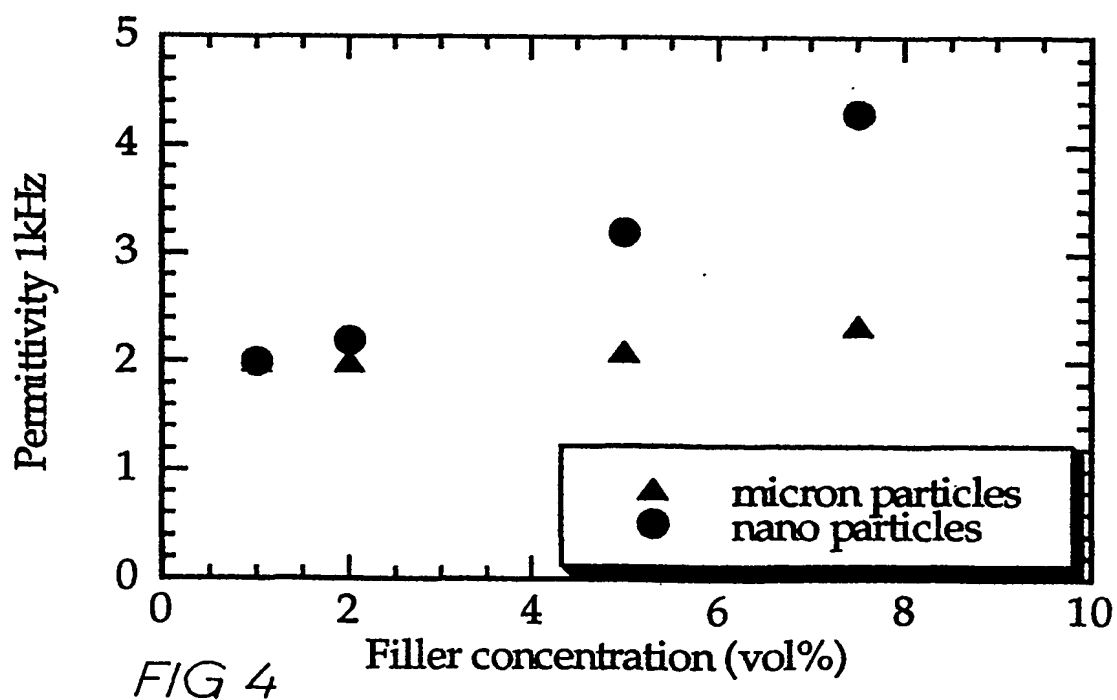
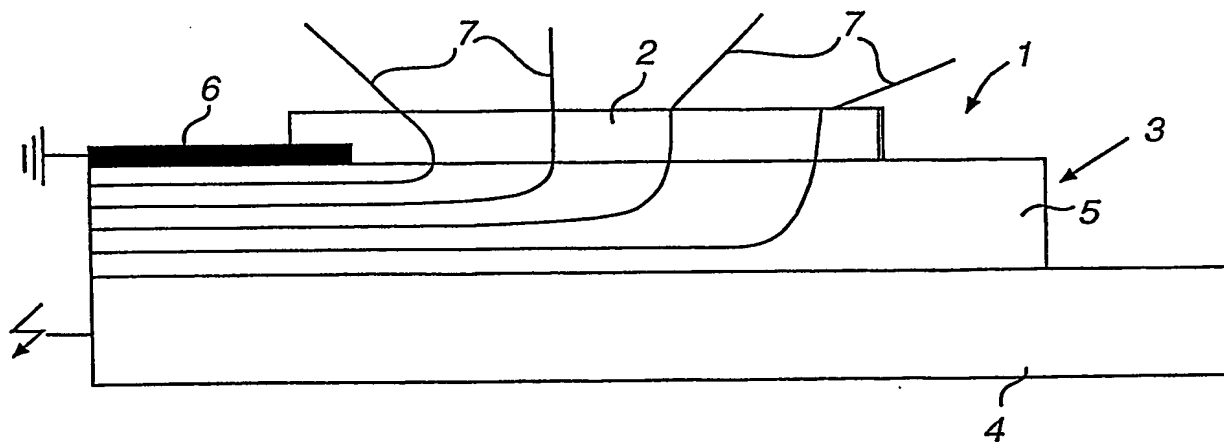
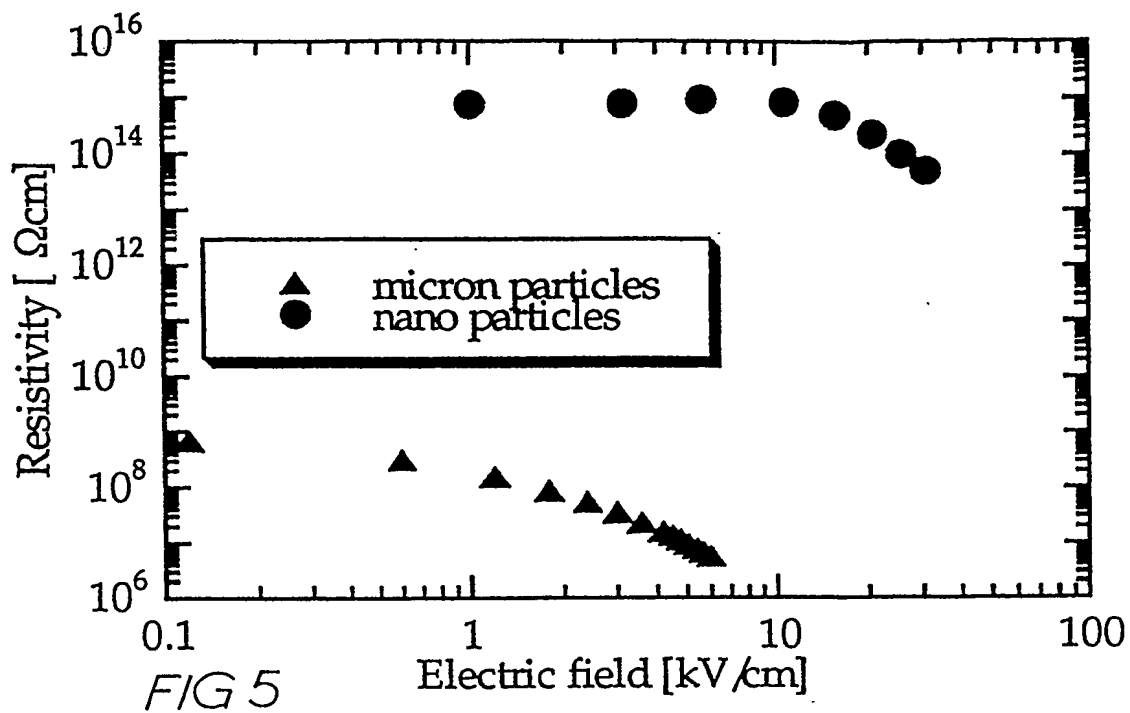


FIG 4

3/3



## INTERNATIONAL SEARCH REPORT

International application No.

PCT/SE 03/01615

<b>A. CLASSIFICATION OF SUBJECT MATTER</b>		
<b>IPC7: H01B 9/02, C08K 3/00</b> According to International Patent Classification (IPC) or to both national classification and IPC		
<b>B. FIELDS SEARCHED</b>		
Minimum documentation searched (classification system followed by classification symbols)		
<b>IPC7: H01B, C08K</b>		
Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched		
<b>SE,DK,FI,NO classes as above</b>		
Electronic data base consulted during the international search (name of data base and, where practicable, search terms used)		
<b>C. DOCUMENTS CONSIDERED TO BE RELEVANT</b>		
Category*	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
<b>X</b>	<b>PATENT ABSTRACTS OF JAPAN</b> vol.199, no. 810 31 August 1998 (1998-08-31) & JP 10 116702 A (FURUKAWA ELECTRIC CO LTD) 06 May 1998 (1998-05-06) abstract see section 0002-0003-0006-0009 --	<b>1-2,5,8-13</b>
<b>A</b>	<b>US 2002070428 A1 (BERNHOF ET AL), 13 June 2002</b> (13.06.02), see section 0008-0023,0037-0038 --	<b>1-13</b>
<input checked="" type="checkbox"/> Further documents are listed in the continuation of Box C. <input checked="" type="checkbox"/> See patent family annex.		
* Special categories of cited documents: "A" document defining the general state of the art which is not considered to be of particular relevance "E" earlier application or patent but published on or after the international filing date "L" document which may throw doubts on priority claim(s) or which is cited to establish the publication date of another citation or other special reason (as specified) "O" document referring to an oral disclosure, use, exhibition or other means "P" document published prior to the international filing date but later than the priority date claimed "T" later document published after the international filing date or priority date and not in conflict with the application but cited to understand the principle or theory underlying the invention "X" document of particular relevance: the claimed invention cannot be considered novel or cannot be considered to involve an inventive step when the document is taken alone "Y" document of particular relevance: the claimed invention cannot be considered to involve an inventive step when the document is combined with one or more other such documents, such combination being obvious to a person skilled in the art "&" document member of the same patent family		
Date of the actual completion of the international search		Date of mailing of the international search report
<b>4 December 2003</b>		<b>13 -01- 2004</b>
Name and mailing address of the ISA/ Swedish Patent Office Box 5055, S-102 42 STOCKHOLM Facsimile No. +46 8 666 02 86		Authorized officer  <b>FREDRIK WAHLIN/MN</b> Telephone No. +46 8 782 25 00

## INTERNATIONAL SEARCH REPORT

International application No.

PCT/SE 03/01615

## C (Continuation). DOCUMENTS CONSIDERED TO BE RELEVANT

Category*	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
A	<p>Solid Dielectrics, 2001. ISCD '01. Proceedings IEEE 7th International Conference on pages 43-45, Onneby C. et al, "Electrical properties of field grading materials influence silicon carbide grain size" ISBN:0-7803-6352-3, see page 43</p> <p>-- -----</p>	1-13

INTERNATIONAL SEARCH REPORT  
Information on patent family members

06/09/03

International application No.  
PCT/SE 03/01615

Patent document cited in search report	Publication date	Patent family member(s)	Publication date
US 2002070428 A1	13/06/02	NONE	